



40V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C
-40V	25mΩ @ V _{GS} = -10V	-7.2A
-40 V	$45m\Omega @ V_{GS} = -4.5V$	-5.4A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Motor controls
- Backlighting
- DC-DC converters
- Printer equipment

Features and Benefits

- Low RDS(ON) Minimizes Conduction Losses
- Fast Switching Speed Minimizes Switching Losses
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP4025SFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

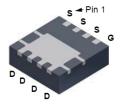
Mechanical Data

- Package: PowerDI[®]3333-8
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Lead Frame.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.0172 grams (Approximate)

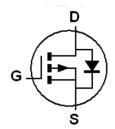




Top View



Bottom View



Device Symbol

Ordering Information (Note 4)

Part Number	Paakaga	Packing			
Part Number	Package	Qty.	Carrier		
DMP4025SFGQ-7	PowerDI3333-8	2,000	Reel		
DMP4025SFGQ-13	PowerDI3333-8	3,000	Reel		

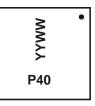
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site 1



P40 = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 23 = 2023)WW = Week (01 to 53)

Site 2



P40 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 3 = 2023)

W = Week (ex: a = Week 27; z Represents Week 52 and 53)

X = Internal Code (ex: U = Monday)

Date Code Key

Year		2014	 2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code)	4	 3	4	5	6	7	8	9	0	1	2

Week	1-26	27-52	53
Code	A-Z	a-z	Z

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	Т	U	V	W	X	Υ	Z

Characteristi	С	Symbol	Value	Unit
Drain-Source Voltage	VDSS	-40		
Gate-Source Voltage	V _{GSS}	±20	V	
	(Note 6)		-7.2	
Continuous Drain Current, VGS = -10V	$T_A = +70^{\circ}C$ (Note 6)	ID	-5.77	
	(Note 5)		-4.65	
Maximum Body Diode Forward Current	(Note 6)	Is	-7.2	A
Pulsed Drain Current	(Note 7)	I _{DM}	-80	
Pulsed Source Current	(Note 7)	Ism	-80	

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

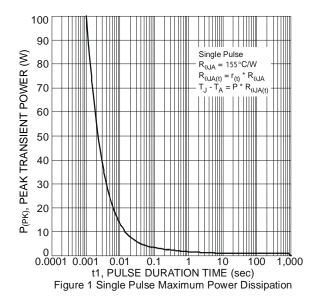
Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	PD	0.81	14/
Linear Derating Factor	Derating Factor (Note 6)		1.95	W
Thermal Desistance Junction to Ambient	(Note 5)	D	155	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	Reja	64	C/VV
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Notes:

- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
- 6. For a device surface mounted on 25mm x 25mm FR-4 PCB with 2oz copper, in still air conditions.
- 7. Same as note (6), except the device is pulsed with D= 0.02 and pulse width 300µs.



Thermal Characteristics



1 D=0.5 D=0.9 r(t), TRANSIENT THERMAL RESISTANCE D=0.7 D=0.3 0.1 D=0.02 0.01 D=0.01 D=0.005 $R_{\theta JA}(t) = r(t) * R_{\theta JA}$ $R_{\theta JA} = 64^{\circ}C/W$ Duty Cycle, D = t1 / t2 D=Single Pulse 0.001 1E-06 1E-05 0.0001 0.001 0.01 0.1 10 100 1000 t1, PULSE DURATION TIME (sec)

Figure 2. Transient Thermal Resistance



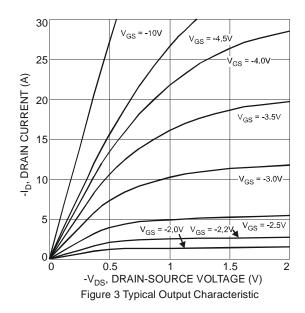
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

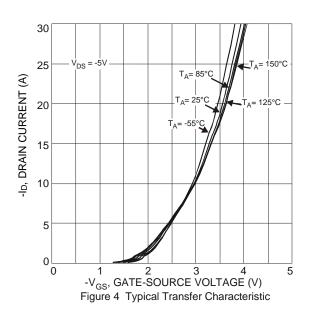
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_		V	$I_D = -250 \mu A$, $V_{GS} = 0 V$
Zero Gate Voltage Drain Current	IDSS	_	_	-1.0	μΑ	$V_{DS} = -40V$, $V_{GS} = 0V$
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS						
Gate Threshold Voltage	Vgs(TH)	-0.8	-1.3	-1.8	V	$I_D = -250\mu A$, $V_{DS} = V_{GS}$
Static Drain-Source On-Resistance (Note 8)	Provous		18	25	mΩ	$V_{GS} = -10V, I_D = -3A$
Static Dialit-Source Off-Resistance (Note 8)	RDS(ON)		30	45	11177	$V_{GS} = -4.5V$, $I_{D} = -3A$
Forward Transconductance (Notes 8 & 9)	g fs	1	16.6	_	S	$V_{DS} = -5V, I_{D} = -3A$
Diode Forward Voltage (Note 8)	VsD	_	-0.7	-1.0	V	Is = -1A, VGS = 0V
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss		1643	_		.,
Output Capacitance	Coss	_	179	_	pF	V _{DS} = -20V, V _{GS} = 0V f = 1MHz
Reverse Transfer Capacitance	Crss	_	128	_		1 = 11011 12
Gate Resistance	R_g	_	6.43	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge (Note 10)	Q_g	_	14.0	_		V _{GS} = -4.5V
Total Gate Charge (Note 10)	Qg	_	33.7	_		V _{DS} = -20V
Gate-Source Charge (Note 10)	Qgs	_	5.5	_	nC	$V_{GS} = -10V$ $I_{D} = -3A$
Gate-Drain Charge (Note 10)	Q _{gd}	_	7.3			
Turn-On Delay Time (Note 10)	tD(ON)	_	6.9	_		
Turn-On Rise Time (Note 10)	t _R	_	14.7]	V _{DD} = -20V, V _{GS} = -10V
Turn-Off Delay Time (Note 10)	tD(OFF)	_	53.7		ns	I _D = -3A
Turn-Off Fall Time (Note 10)	tF	_	30.9			

Notes:

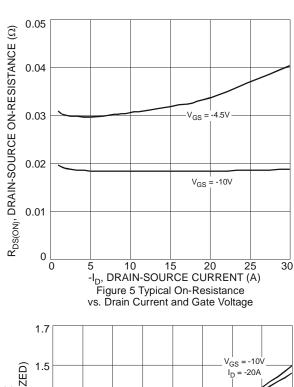
- 8. Measured under pulsed conditions. Pulse width \leq 300µs; duty cycle \leq 2%.
- 9. For design aid only, not subject to production testing.10. Switching characteristics are independent of operating junction temperatures.

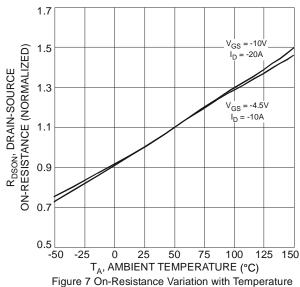
Typical Characteristics











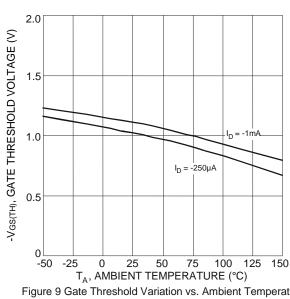
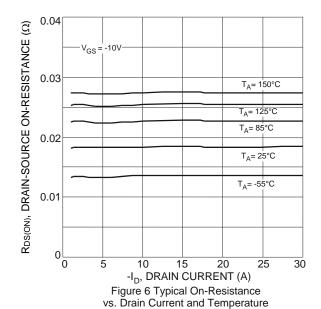
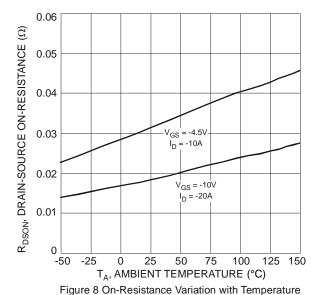


Figure 9 Gate Threshold Variation vs. Ambient Temperature



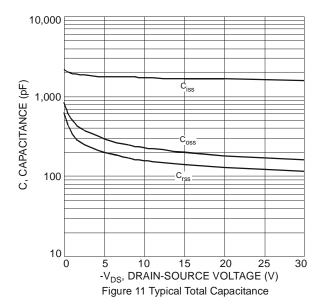


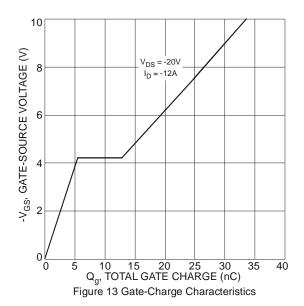
20 18 16 -Is, SOURCE CURRENT (A) 14 12 10 8 2 0 $\begin{array}{ccc} 0.4 & 0.6 & 0.8 & 1.0 \\ \text{-V}_{\text{SD}}, \, \text{SOURCE-DRAIN VOLTAGE (V)} \end{array}$ 0.2

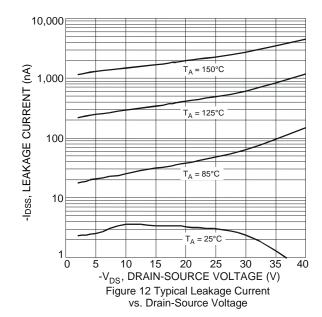
Figure 10 Diode Forward Voltage vs. Current

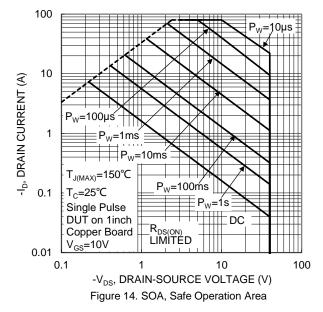










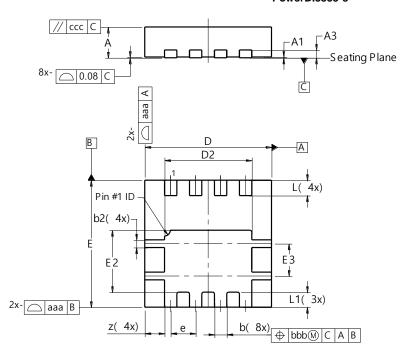




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8

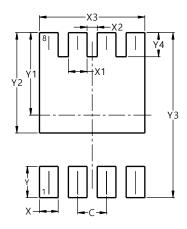


	Powerl	DI3333-	-8		
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3	1	-	0.203		
b	0.27	0.37	0.32		
b2	-	-	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
Е	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
е	1	-	0.65		
L	0.35	0.45	0.40		
L1	_	_	0.39		
Z	_	_	0.515		
aaa	0.25				
bbb		0.10			
CCC	0.10				
All [Dimens	sions ir	n mm		

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
Х3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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